NSN 5961-00-136-8445

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-136-8445 **Inclosure Material:** Metal **Overall Length:** 5.340 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-205aa **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Overall Width Across Flats:** 1.047 inches **Thread Size:** 0.375 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 reverse voltage, peak **Current Rating Per Characteristic:** 150.00 amperes forward current, dc and 2500.00 amperes peak forward surge current **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 insulated wire lead w/terminal lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No